

L Number	Hits	Search Text	DB	Time stamp
-	4841	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:17
-	0	quasi near2 strip near2 like near2 crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:35
-	2	quasi near2 strip near2 like	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:24
-	1188	polycrystalline same recrystallization	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:25
-	0	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.) and (quasi near2 strip near2 like )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:25
-	7080	reformation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:25
-	83908	polycrystalline	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:21
-	6	reformation same polycrystalline	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:27
-	84120	polycrystalline or (p adj si adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:30
-	156387	anneal or annealing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:29
-	5374	(polycrystalline or (p adj si adj (layer or film)) ) same (anneal or annealing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:29
-	681508	laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:29
-	1662	laser same ((polycrystalline or (p adj si adj (layer or film)) ) same (anneal or annealing))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:30
-	2666	lateral near2 growth	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:30

-	23	(laser same ((polycrystalline or (p adj si adj (layer or film)) ) same (anneal or annealing))) same (lateral near2 growth)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:30
-	5	((("200243222") or ("2002100637")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:39
-	202391	irradiate or irradiating	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 21:42
-	89	((irradiate or irradiating) near (polycrystalline or (p adj si adj (layer or film)) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:21
-	5342	((438/30) or (438/128) or (438/149) or (438/166) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:17
-	26893	reform or reformation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:19
-	0	((irradiate or irradiating) near (polycrystalline or (p adj si adj (layer or film)) )) same (reform or reformation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:19
-	0	((irradiate or irradiating) near (polycrystalline or (p adj si adj (layer or film)) )) and (reform or reformation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:19
-	25571	pulse near laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:21
-	369	((pulse near laser) same (polycrystalline or (p adj si adj (layer or film)) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:22
-	177	((pulse near laser) same (polycrystalline or (p adj si adj (layer or film)) )) and (irradiate or irradiating)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:22
-	41017	((polycrystalline or (p adj si)) near2 (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:42
-	41	selective near irradiating	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:34
-	1	((polycrystalline or (p adj si)) near2 (layer or film) ) and (selective near irradiating)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:32

-	17	(irradiate or irradiating) near (selective near irradiating)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:35
-	103	quasi near like	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:35
-	0	((irradiate or irradiating) near ((polycrystalline or (p adj si)) near2 (layer or film) )) and (quasi near like)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:35
-	104	(irradiate or irradiating) near ((polycrystalline or (p adj si)) near2 (layer or film) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:40
-	101	sequential near lateral near solidification	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:41
-	55	(sequential near lateral near solidification) and ((polycrystalline or (p adj si)) near2 (layer or film) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 22:42